

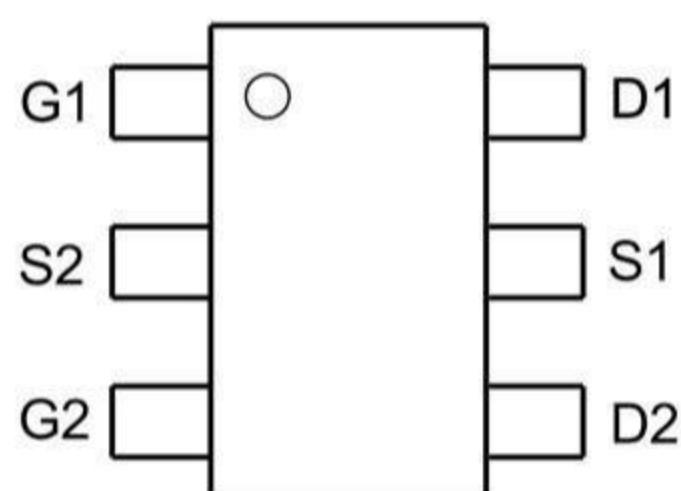
### Product Summary

- N-Channel
- $V_{DS} = 30V, I_D = 4A$
- $R_{DS(ON)} 30m\Omega @ V_{GS}=10V$  (Typ)
- $R_{DS(ON)} 50m\Omega @ V_{GS}=-4.5V$  (Typ)
- P-Channel
- $V_{DS} = -30V, I_D = 3A$
- $R_{DS(ON)} 45m\Omega @ V_{GS}=-10V$  (Typ)
- $R_{DS(ON)} 85m\Omega @ V_{GS}=-4.5V$  (Typ)

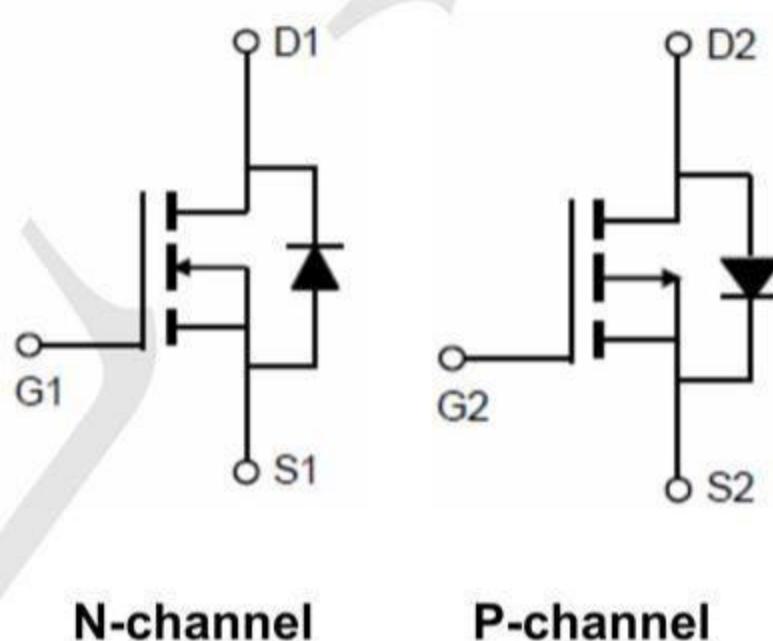
### Application

- DC-DC Converters.
- Load Switch.
- Power Management.

### Package and Pin Configuration



### Circuit diagram



Marking:66G

### Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	N-Channel	P-Channel	Unit
Drain-Source Voltage	$V_{DS}$	30	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	$\pm 20$	V
Continuous Drain Current	$I_D$	4.0	-3.0	A
		3	-2.1	
Pulsed Drain Current <sup>(Note 1)</sup>	$I_{DM}$	20	-15	A
Maximum Power Dissipation	$P_D$	1.2		W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	-55 To 150	°C

### Thermal Characteristic

Thermal Resistance, Junction-to-Ambient <sup>(Note2)</sup>	$R_{\theta JA}$	N-Ch	104	°C/W
Thermal Resistance, Junction-to-Ambient <sup>(Note2)</sup>	$R_{\theta JA}$	P-Ch	104	°C/W

**N-CH Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	30		-	V
Zero Gate Voltage Drain Current	$\text{I}_{\text{DSS}}$	$\text{V}_{\text{DS}}=30\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	-	1	$\mu\text{A}$
Gate-Body Leakage Current	$\text{I}_{\text{GSS}}$	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	$\pm 100$	nA
<b>On Characteristics</b> (Note 3)						
Gate Threshold Voltage	$\text{V}_{\text{GS}(\text{th})}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	1.2	1.5	2.2	V
Drain-Source On-State Resistance	$\text{R}_{\text{DS}(\text{ON})}$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=4\text{A}$		30	48	$\text{m}\Omega$
		$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=2\text{A}$		50	90	$\text{m}\Omega$
Forward Transconductance	$\text{g}_{\text{FS}}$	$\text{V}_{\text{DS}}=5\text{V}, \text{I}_D=3.1\text{A}$	-	4	-	S
<b>Dynamic Characteristics</b> (Note 4)						
Input Capacitance	$\text{C}_{\text{iss}}$	$\text{V}_{\text{DS}}=15\text{V}, \text{V}_{\text{GS}}=0\text{V},$ $F=1.0\text{MHz}$	-	210	-	PF
Output Capacitance	$\text{C}_{\text{oss}}$		-	35	-	PF
Reverse Transfer Capacitance	$\text{C}_{\text{rss}}$		-	23	-	PF
<b>Switching Characteristics</b> (Note 4)						
Turn-on Delay Time	$t_{\text{d}(\text{on})}$	$\text{V}_{\text{DD}}=15\text{V}, \text{R}_L=3\Omega$ $\text{V}_{\text{GS}}=10\text{V}, \text{R}_{\text{GEN}}=6\Omega$	-	4.5	-	nS
Turn-on Rise Time	$t_r$		-	1.5	-	nS
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	18.5	-	nS
Turn-Off Fall Time	$t_f$		-	15.5	-	nS
Total Gate Charge	$\text{Q}_g$	$\text{V}_{\text{DS}}=15\text{V}, \text{I}_D=3.5\text{A},$ $\text{V}_{\text{GS}}=10\text{V}$	-	5	-	nC
Gate-Source Charge	$\text{Q}_{\text{gs}}$		-	0.55	-	nC
Gate-Drain Charge	$\text{Q}_{\text{gd}}$		-	1	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	$\text{V}_{\text{SD}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_S=3.5\text{A}$	-	0.8	1.2	V
Diode Forward Current (Note 2)	$\text{I}_S$		-	-	4	A

**P-CH Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$	-30	-33	-	V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=-30\text{V}, V_{\text{GS}}=0\text{V}$	-	-	-1	$\mu\text{A}$
Gate-Body Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	$\pm100$	nA
<b>On Characteristics</b> <sup>(Note 3)</sup>						
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$	-1	-1.6	-2.5	V
Drain-Source On-State Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=-10\text{V}, I_{\text{D}}=-2.7\text{A}$	-	45	65	$\text{m}\Omega$
		$V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-2\text{A}$	-	85	100	$\text{m}\Omega$
Forward Transconductance	$g_{\text{FS}}$	$V_{\text{DS}}=-10\text{V}, I_{\text{D}}=-2.7\text{A}$		2	-	S
<b>Dynamic Characteristics</b> <sup>(Note 4)</sup>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=-15\text{V}, V_{\text{GS}}=0\text{V}, F=1.0\text{MHz}$	-	199	-	PF
Output Capacitance	$C_{\text{oss}}$		-	47	-	PF
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	28	-	PF
<b>Switching Characteristics</b> <sup>(Note 4)</sup>						
Turn-on Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=-15\text{V}, R_{\text{L}}=15\Omega$ $V_{\text{GS}}=-10\text{V}, R_{\text{GEN}}=6\Omega$	-	8	-	nS
Turn-on Rise Time	$t_r$		-	5	-	nS
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	12	-	nS
Turn-Off Fall Time	$t_f$		-	4	-	nS
Total Gate Charge	$Q_g$	$V_{\text{DS}}=-15\text{V}, I_{\text{D}}=-2.7\text{A}, V_{\text{GS}}=-10\text{V}$	-	5	-	nC
Gate-Source Charge	$Q_{\text{gs}}$		-	0.7	-	nC
Gate-Drain Charge	$Q_{\text{gd}}$		-	1.1	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <sup>(Note 3)</sup>	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}, I_{\text{S}}=-2.7\text{A}$	-	-	-1.2	V

### N- Channel Typical Electrical and Thermal Characteristics

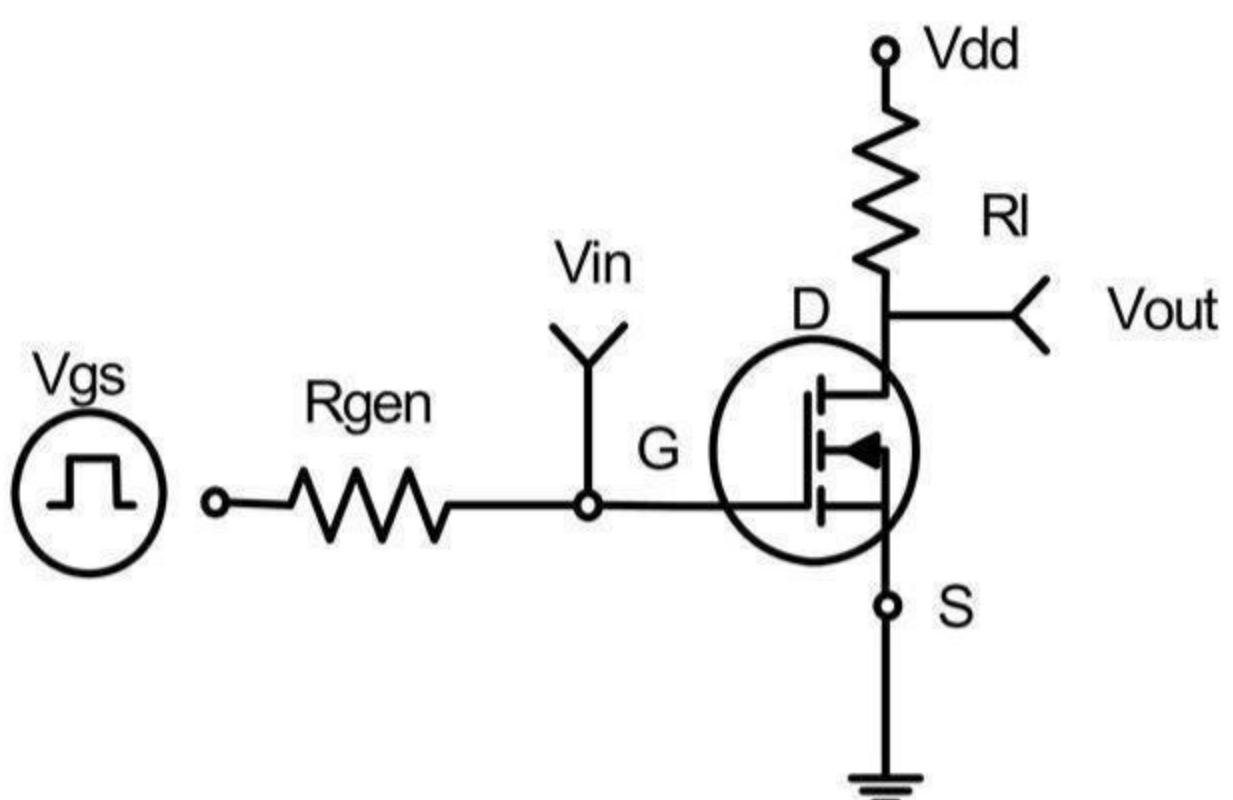


Figure 1:Switching Test Circuit

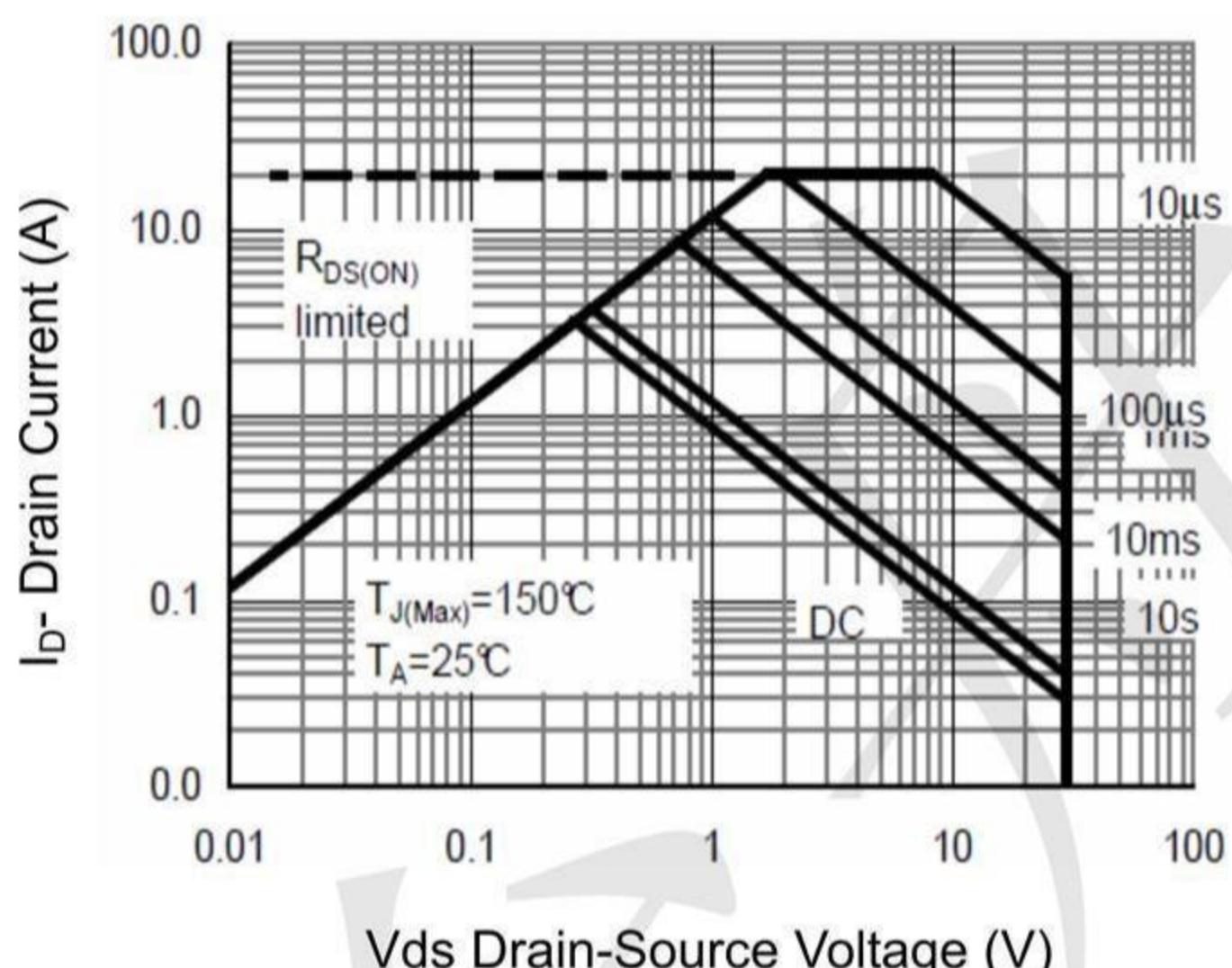


Figure 3 Safe Operation Area

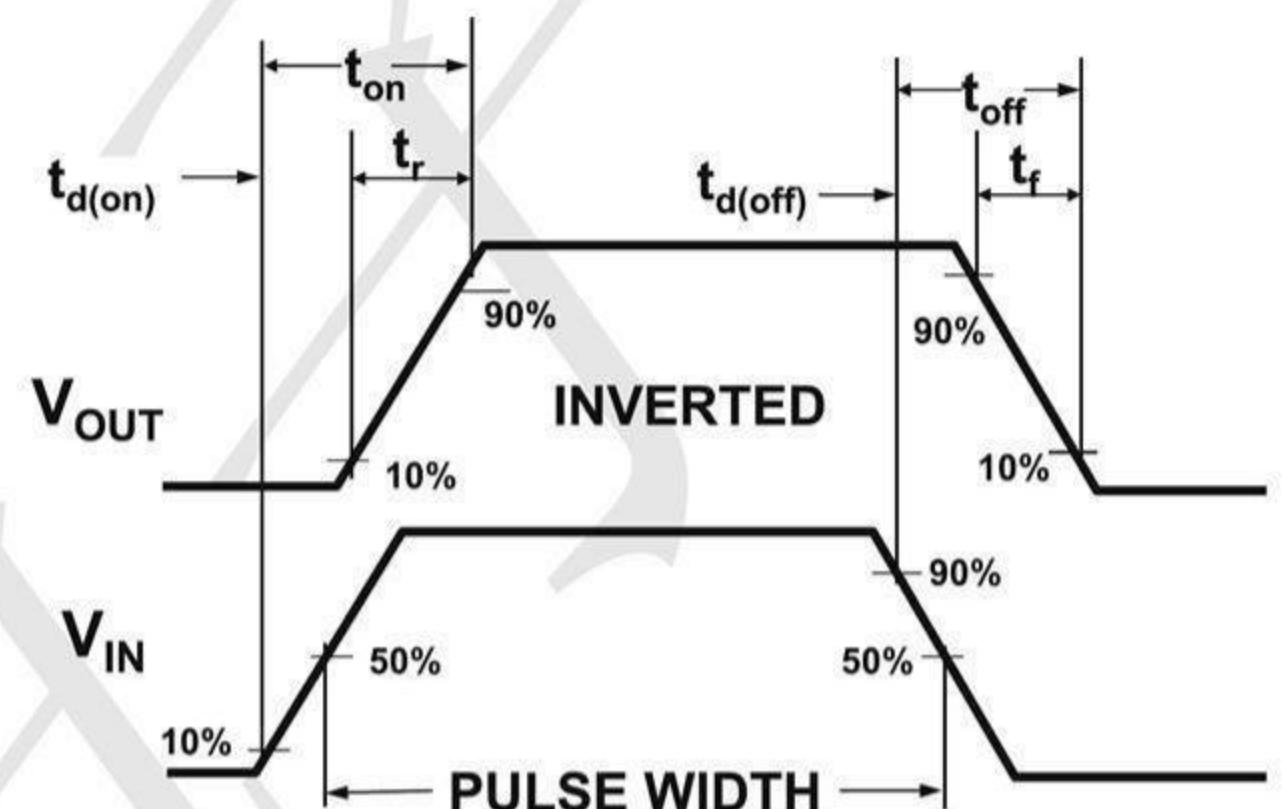
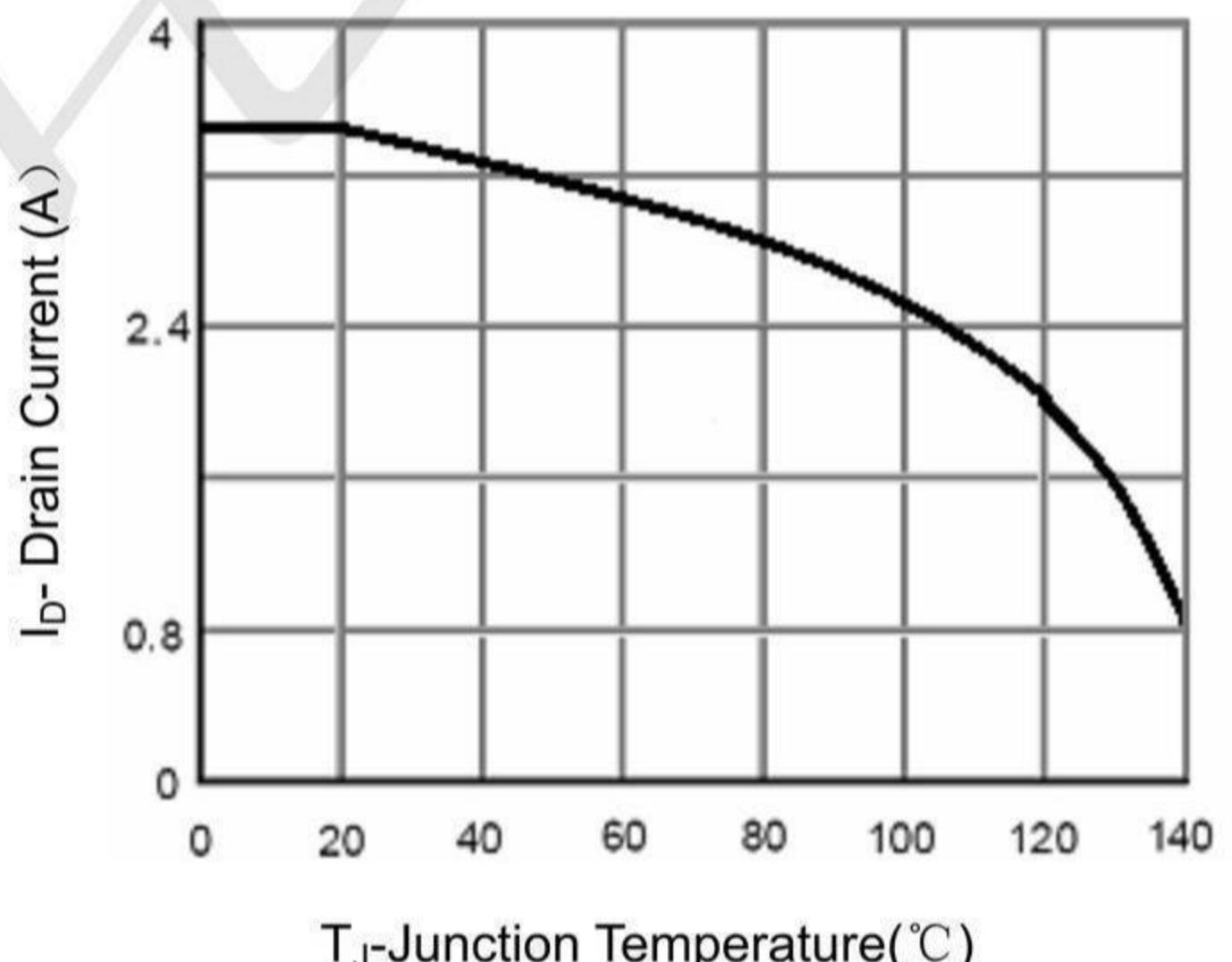


Figure 2:Switching Waveforms



T<sub>J</sub>-Junction Temperature(°C)

Figure 4 Drain Current

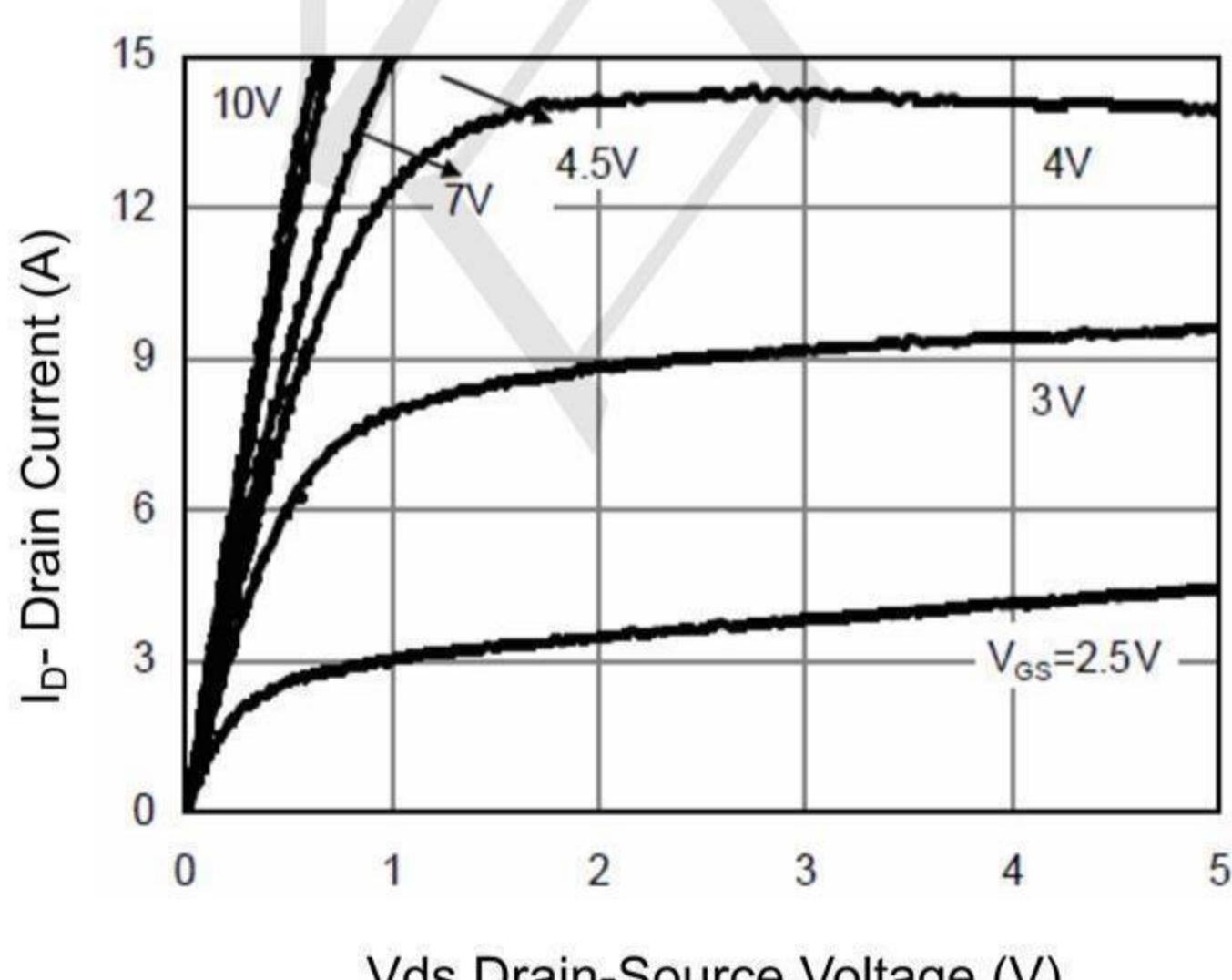


Figure 5 Output Characteristics

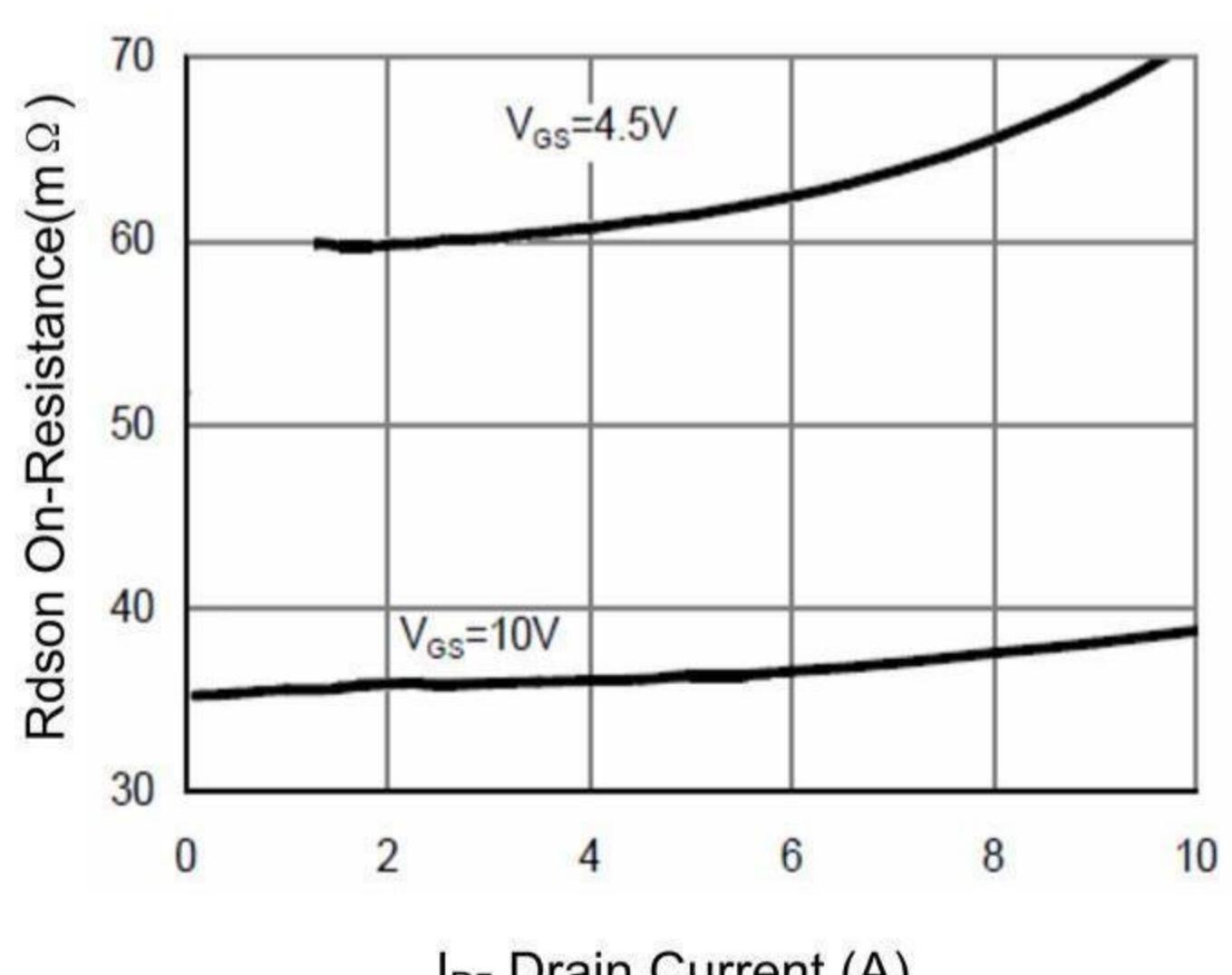
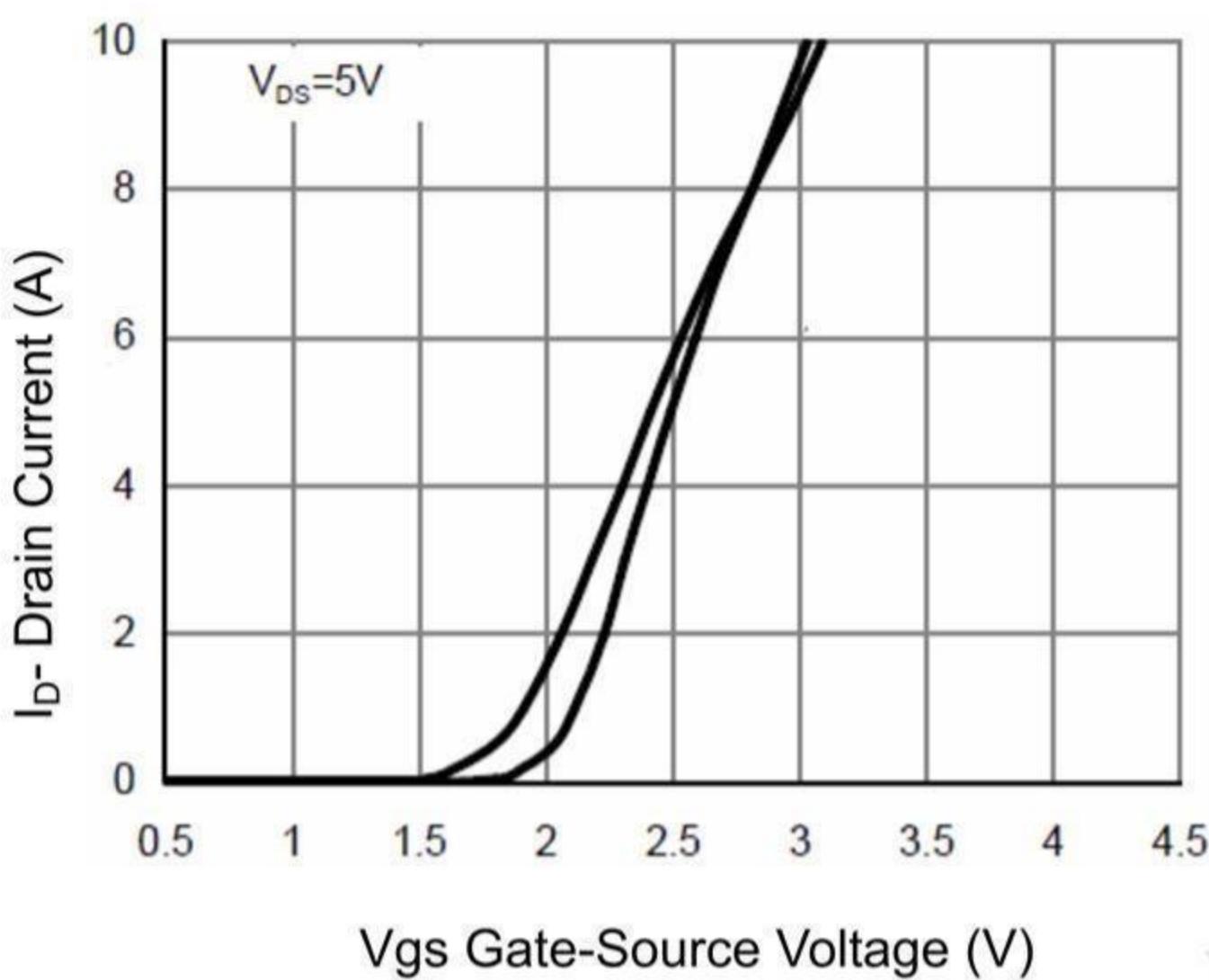
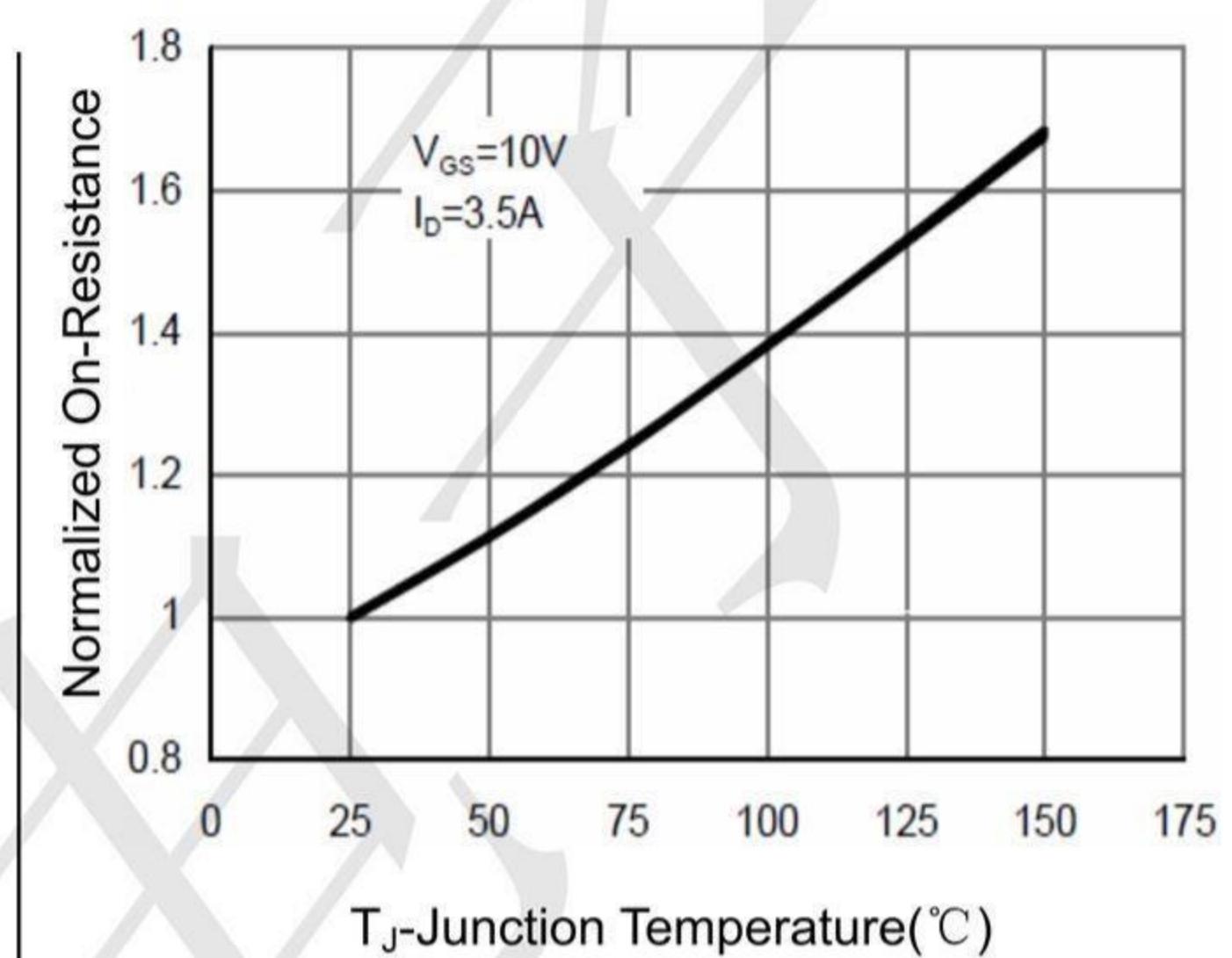


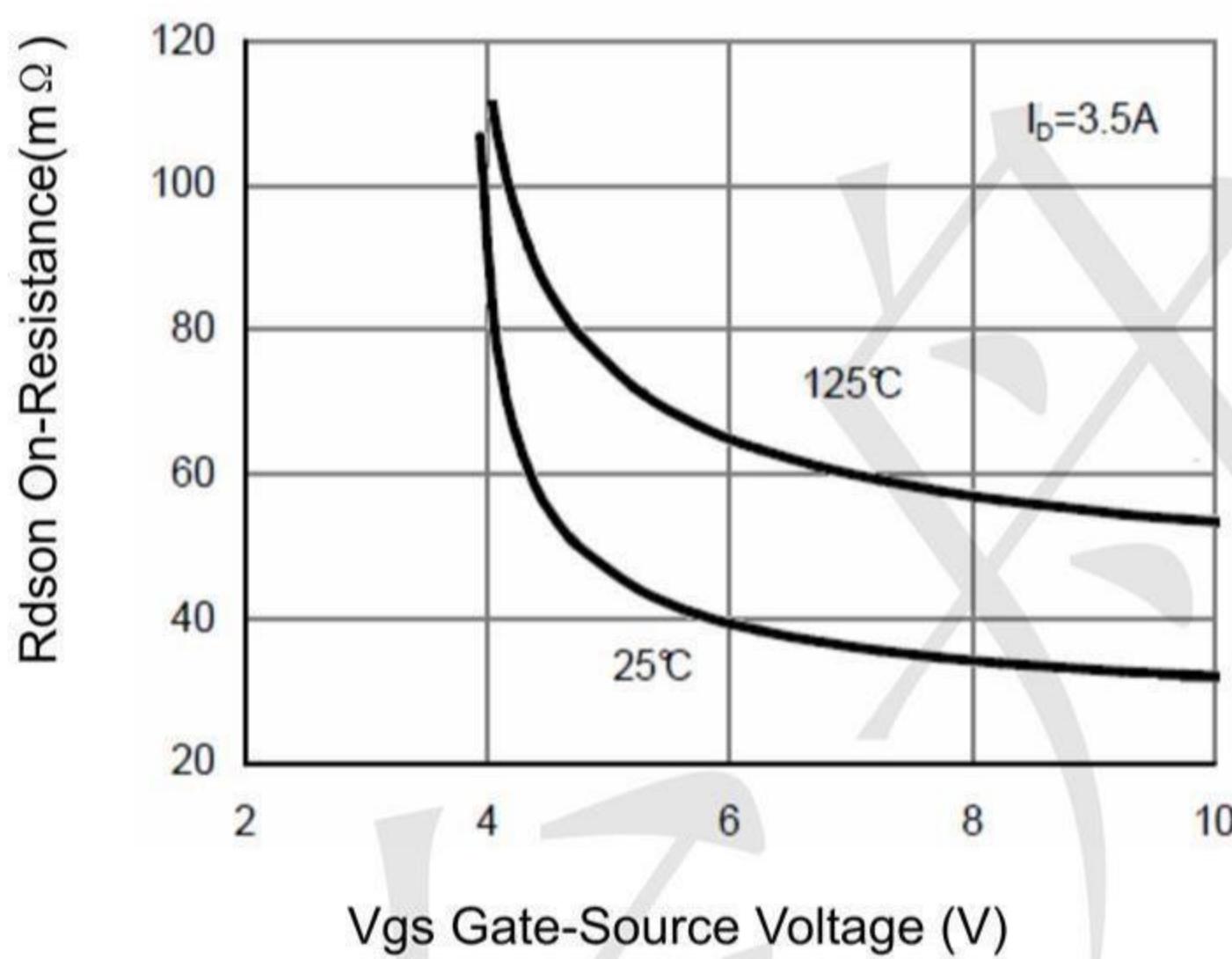
Figure 6 Drain-Source On-Resistance



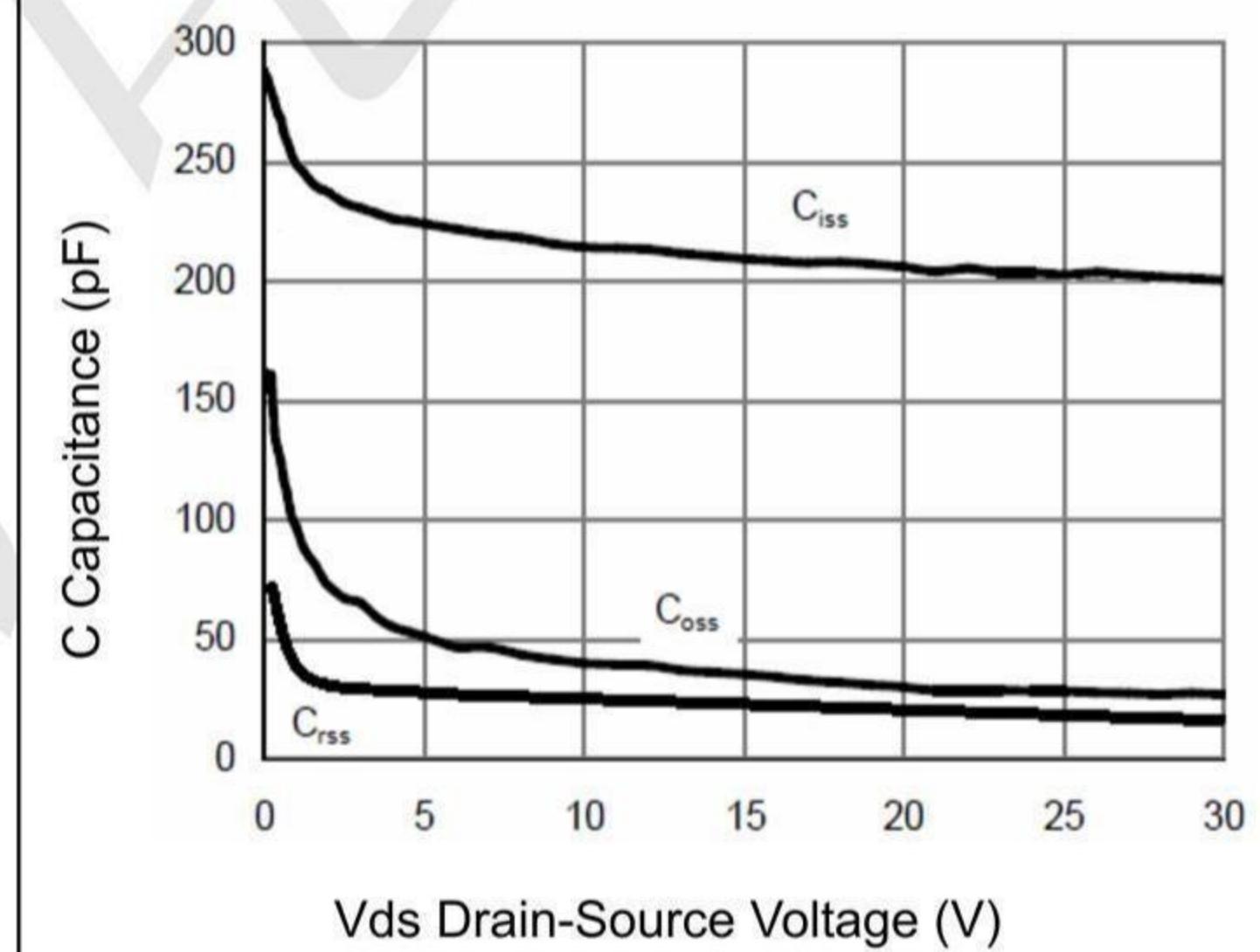
**Figure 7 Transfer Characteristics**



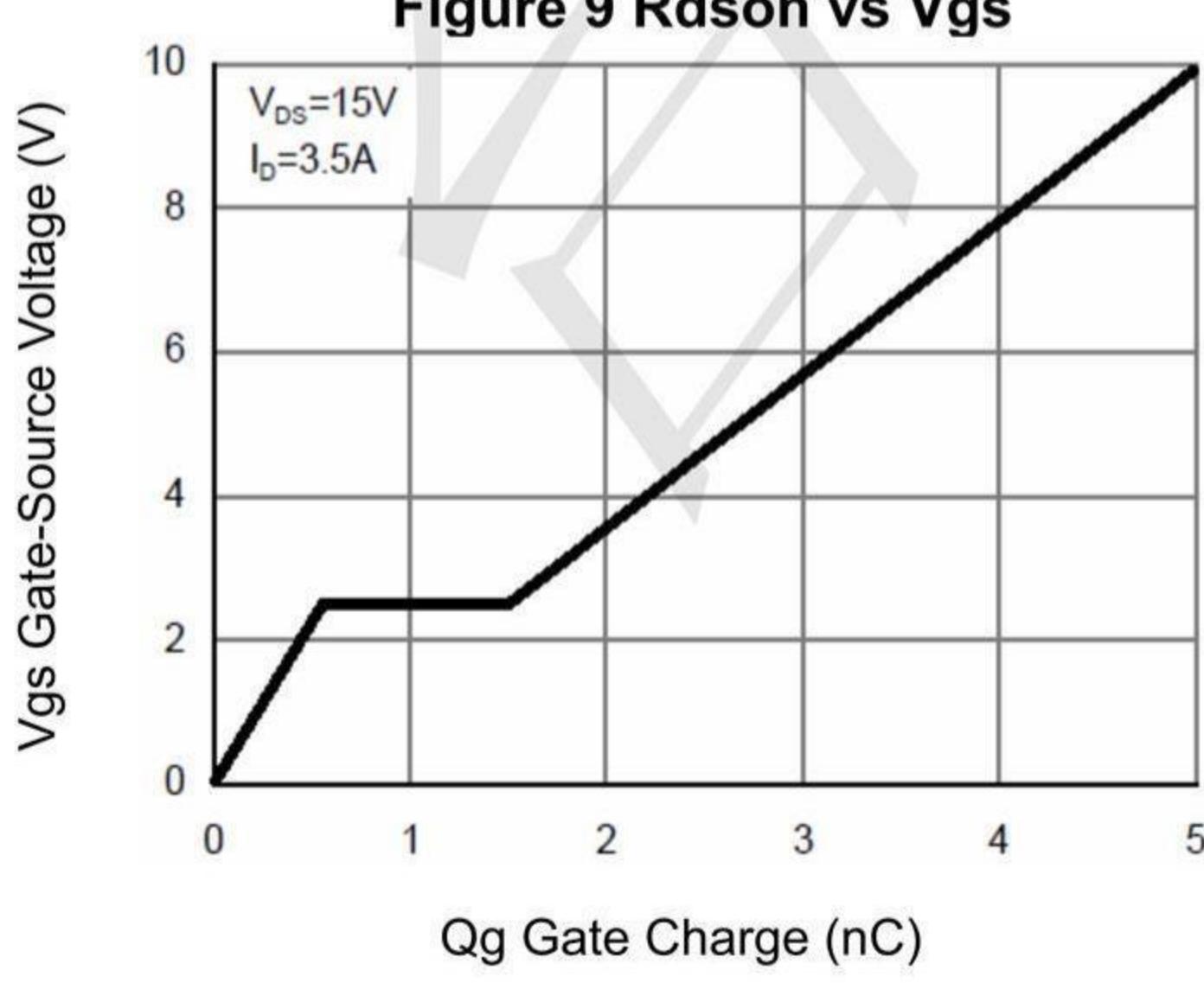
**Figure 8 Drain-Source On-Resistance**



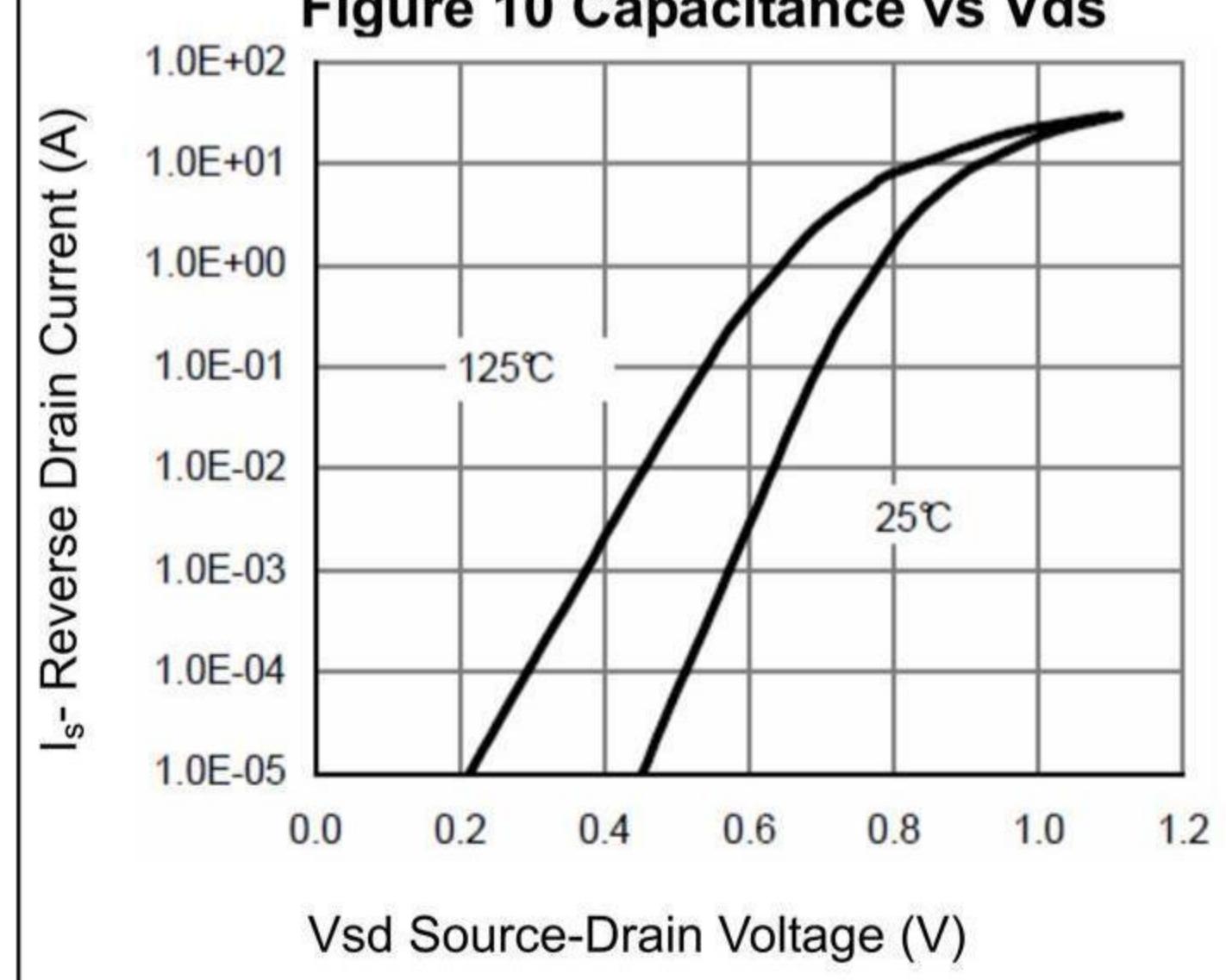
**Figure 9  $R_{DS(on)}$  vs  $V_{GS}$**



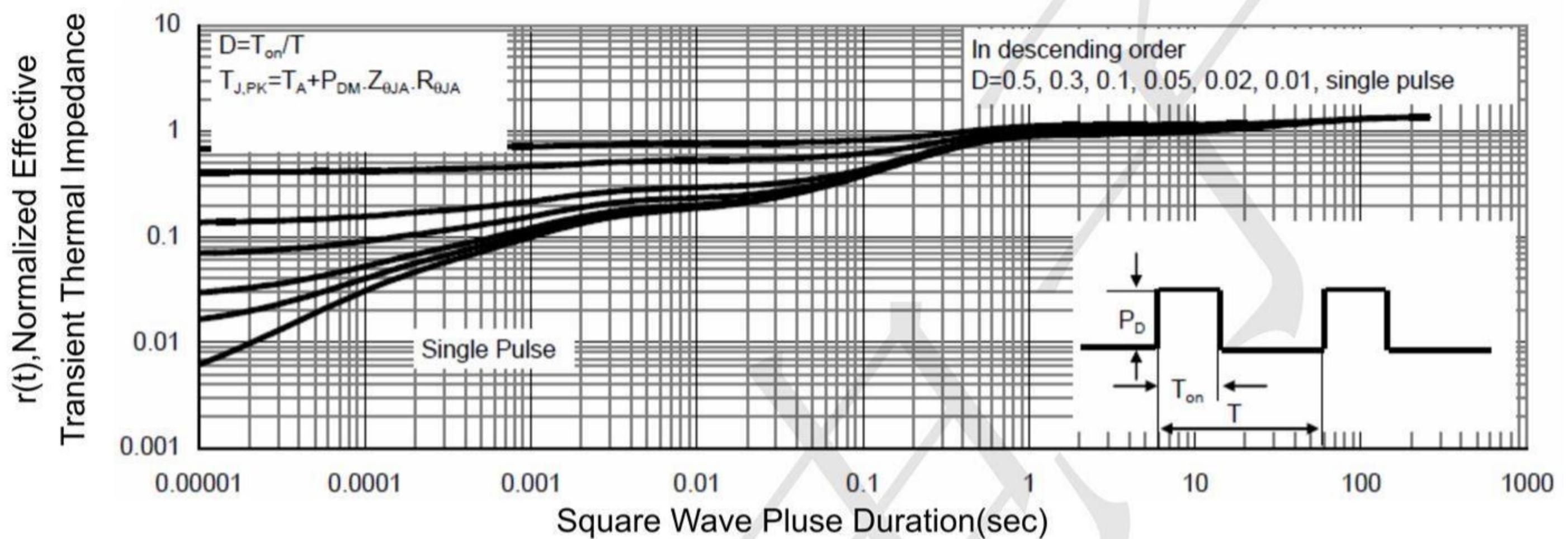
**Figure 10 Capacitance vs  $V_{DS}$**



**Figure 11 Gate Charge**



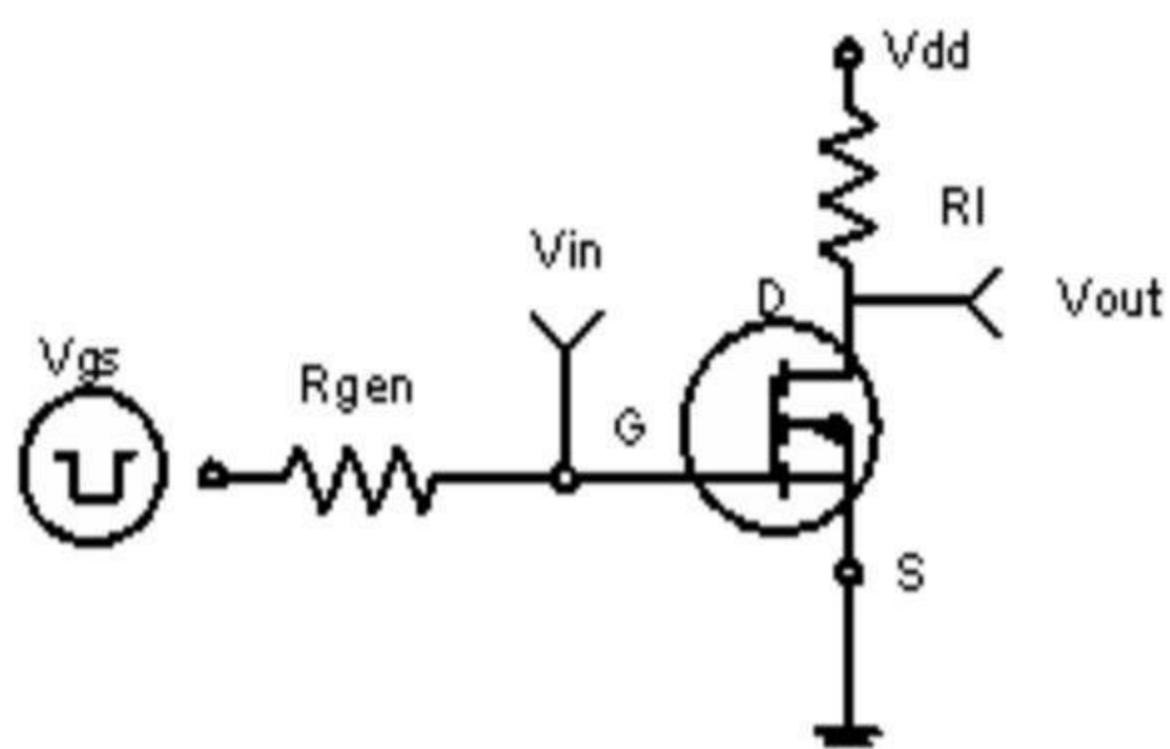
**Figure 12 Source-Drain Diode Forward**



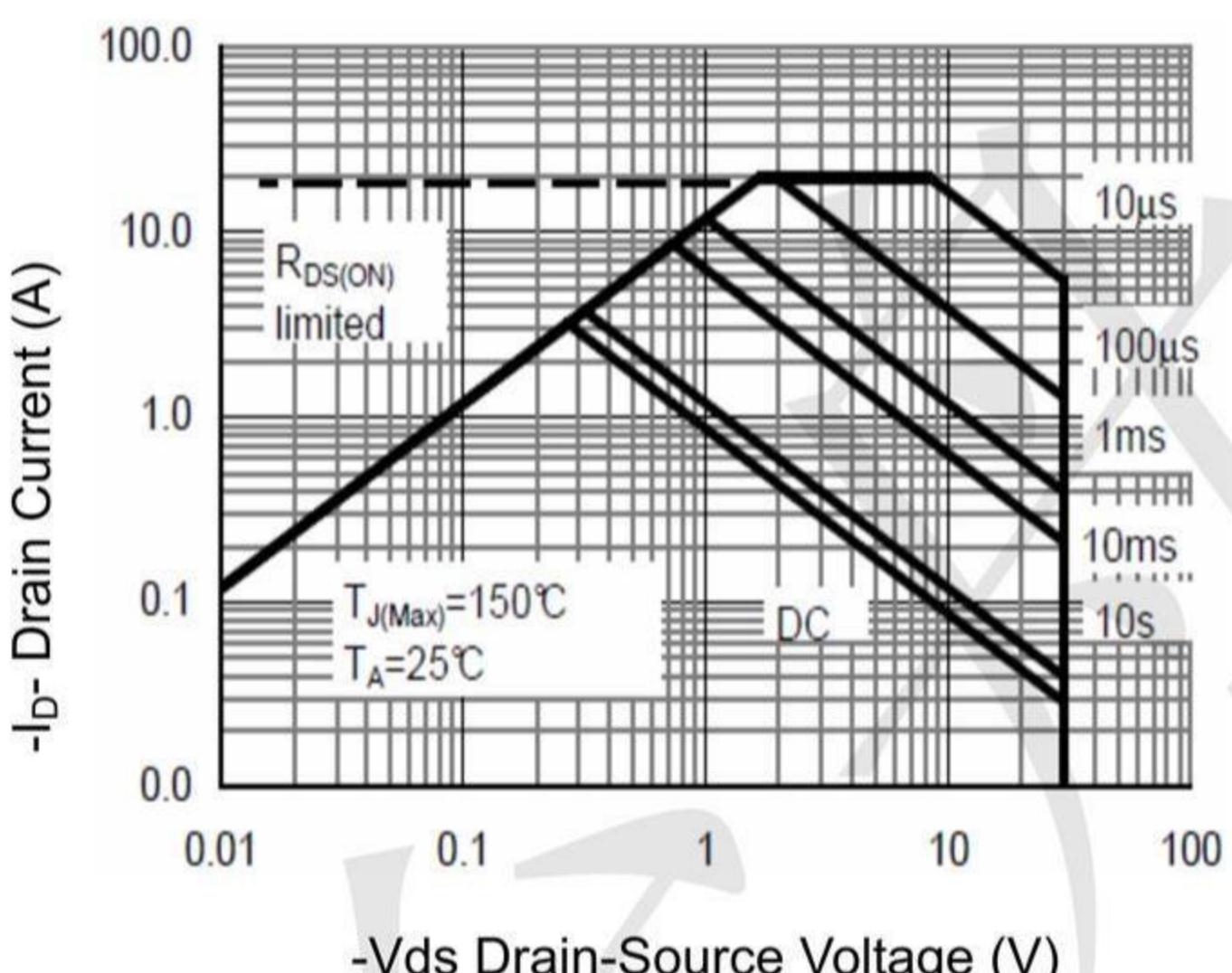
**Figure 13 Normalized Maximum Transient Thermal Impedance**

**P- Channel Typical Electrical and Thermal Characteristics**

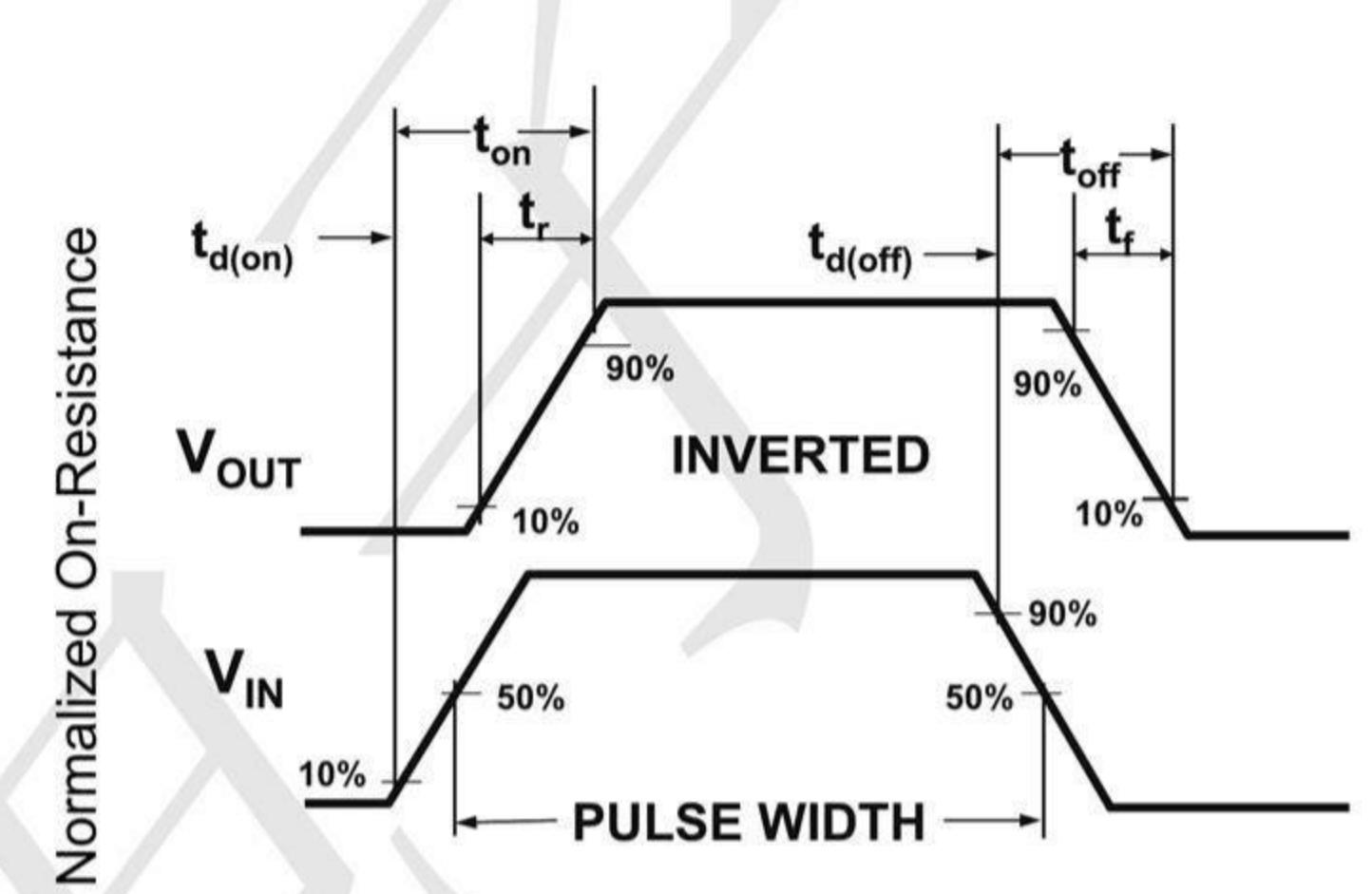
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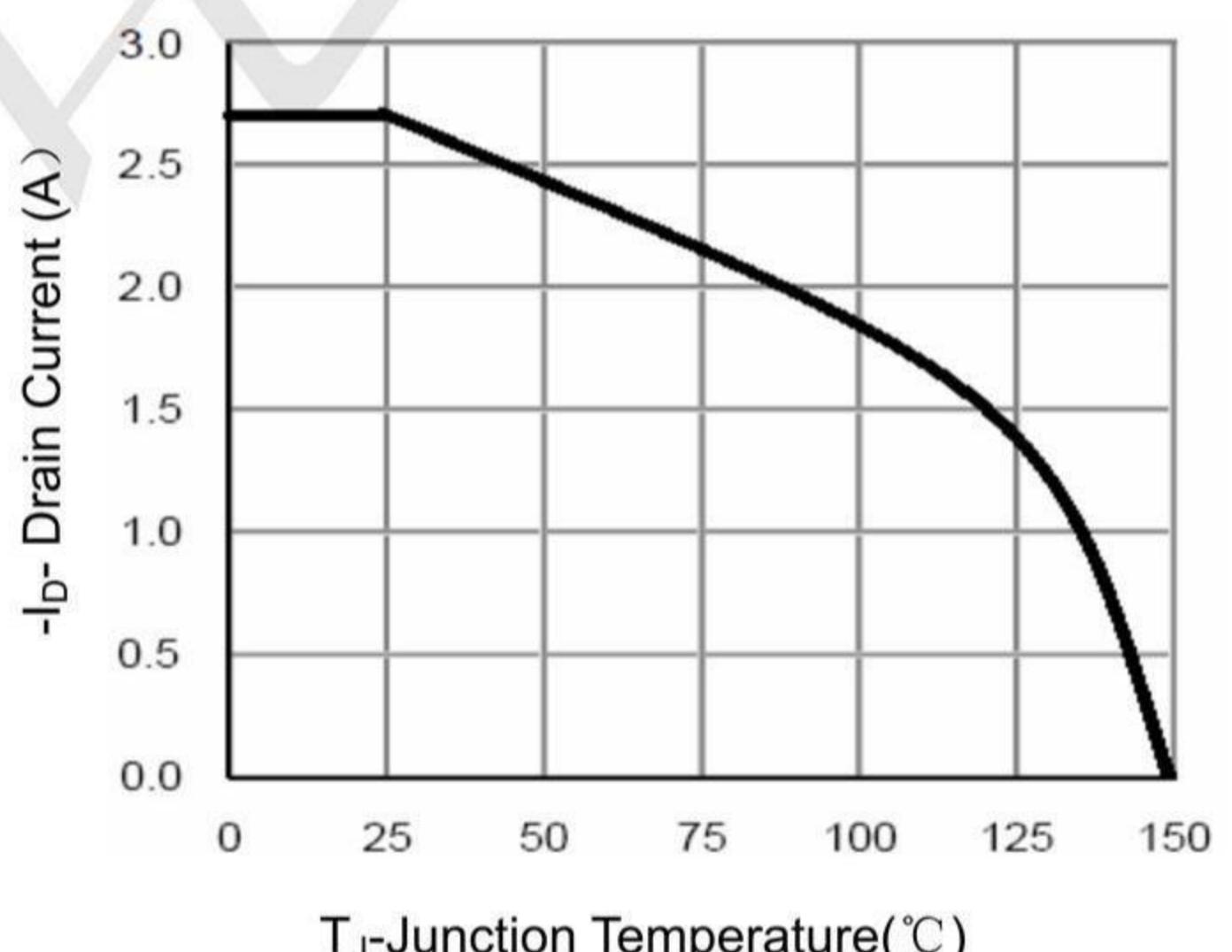
**Figure 1:Switching Test Circuit**



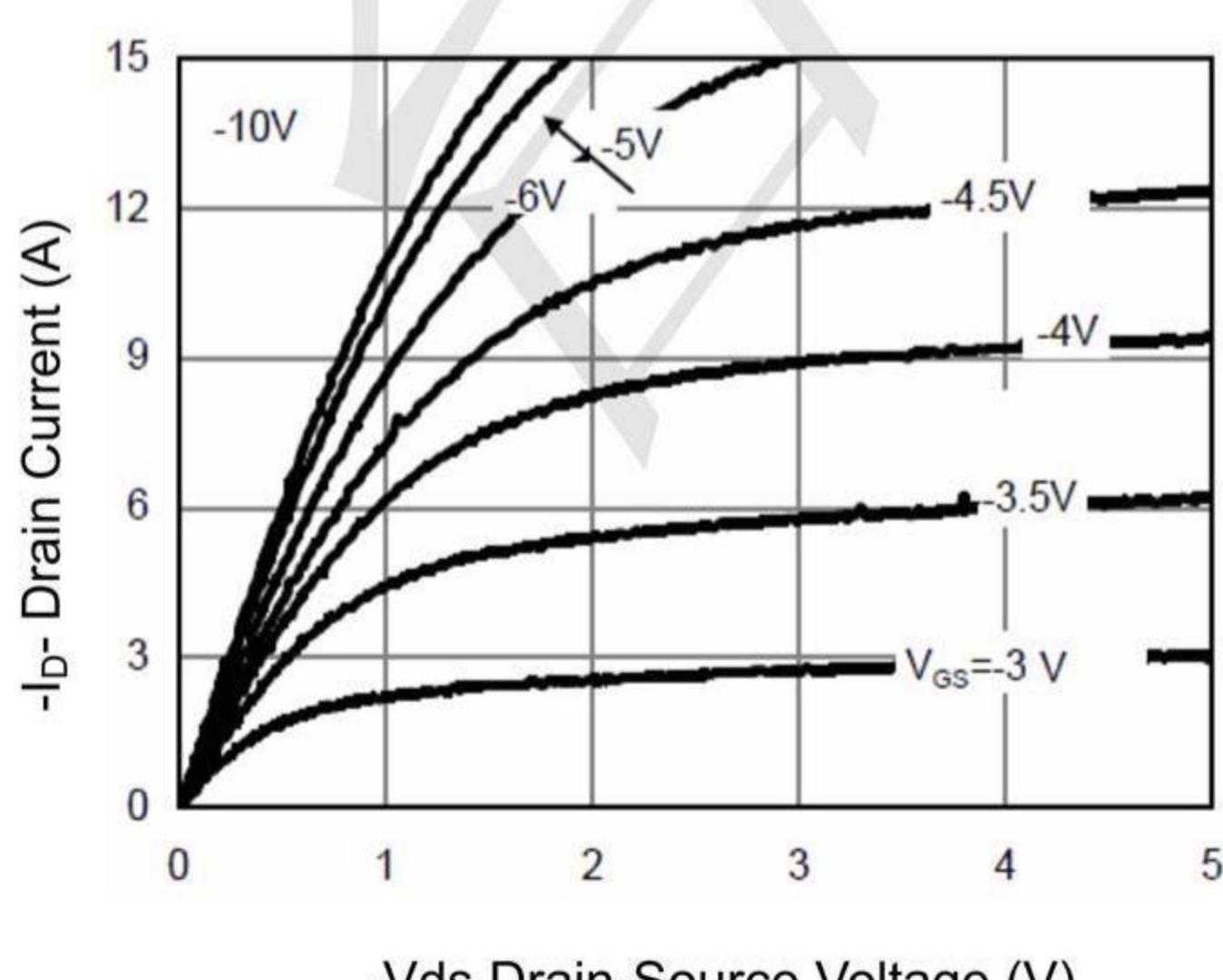
**Figure 3 Safe Operation Area**



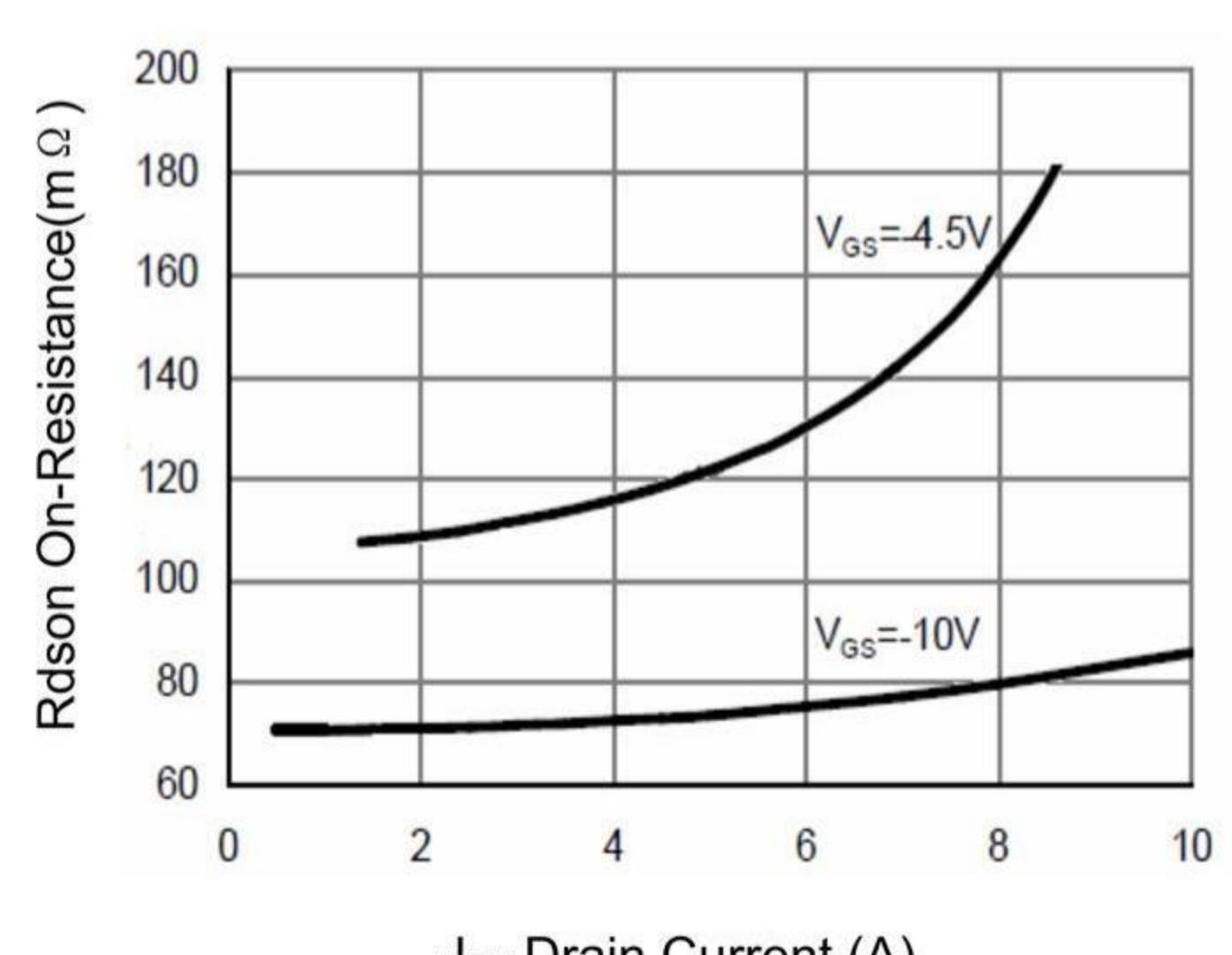
**Figure 2:Switching Waveforms**



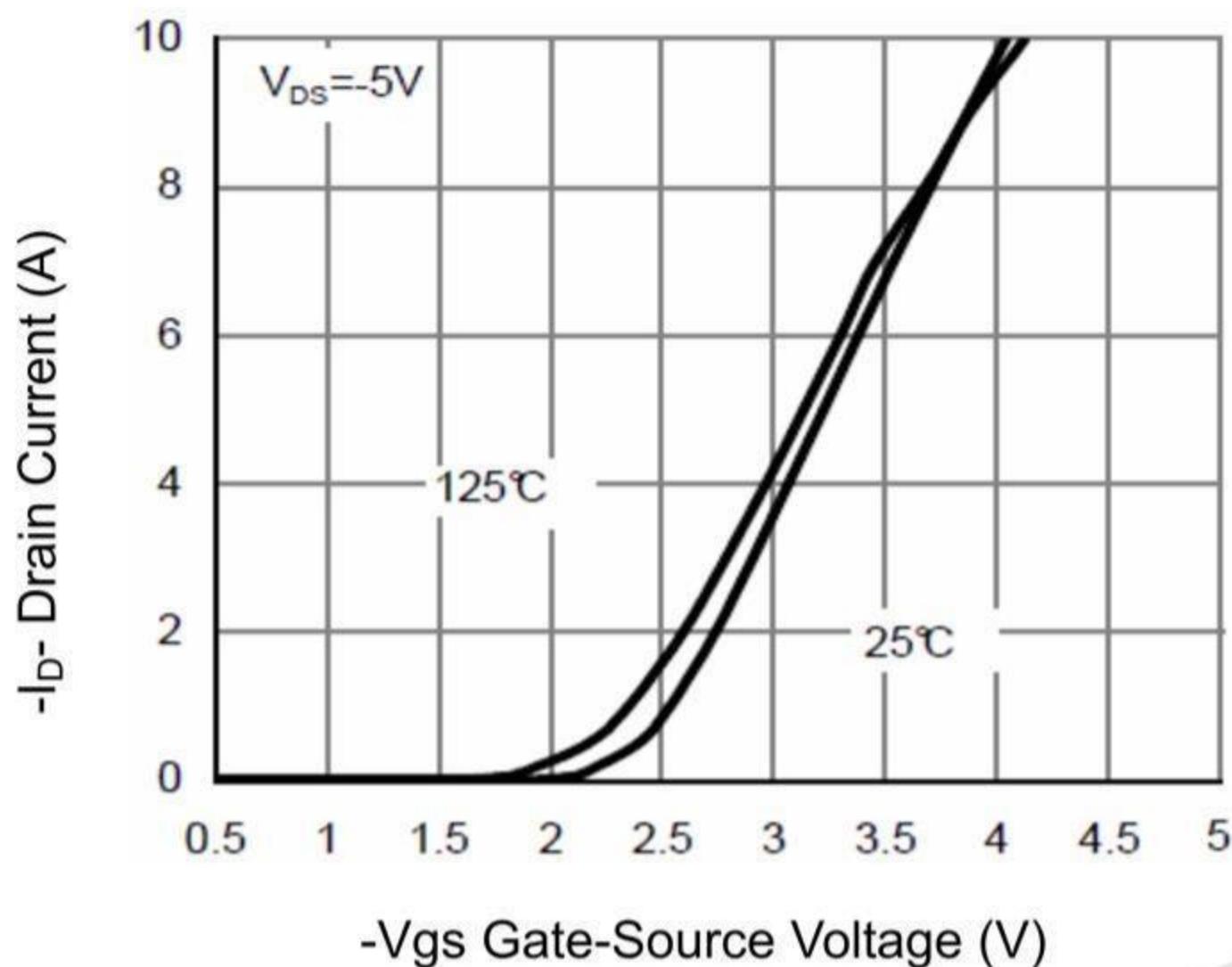
**Figure 4 Drain Current**



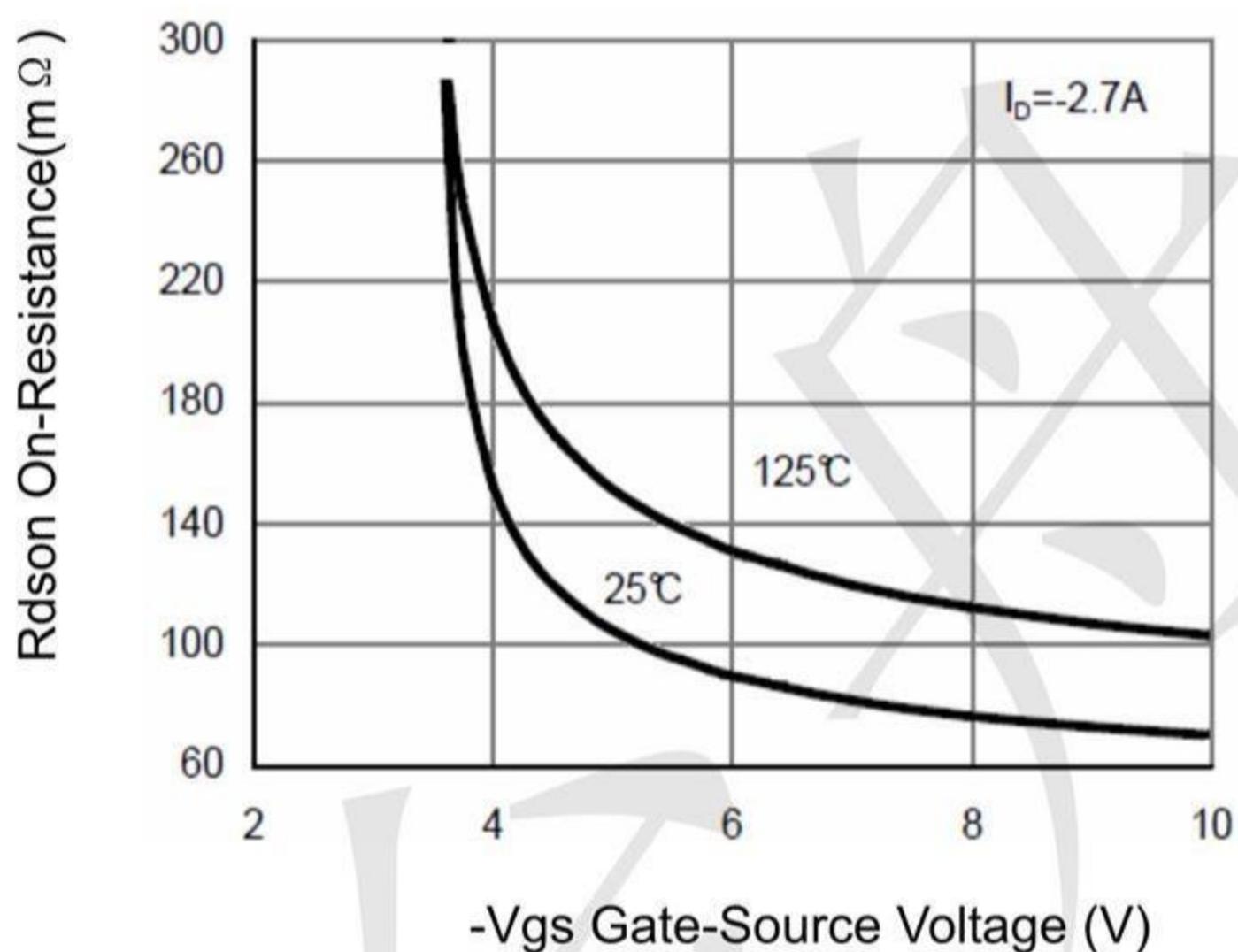
**Figure 5 Output Characteristics**



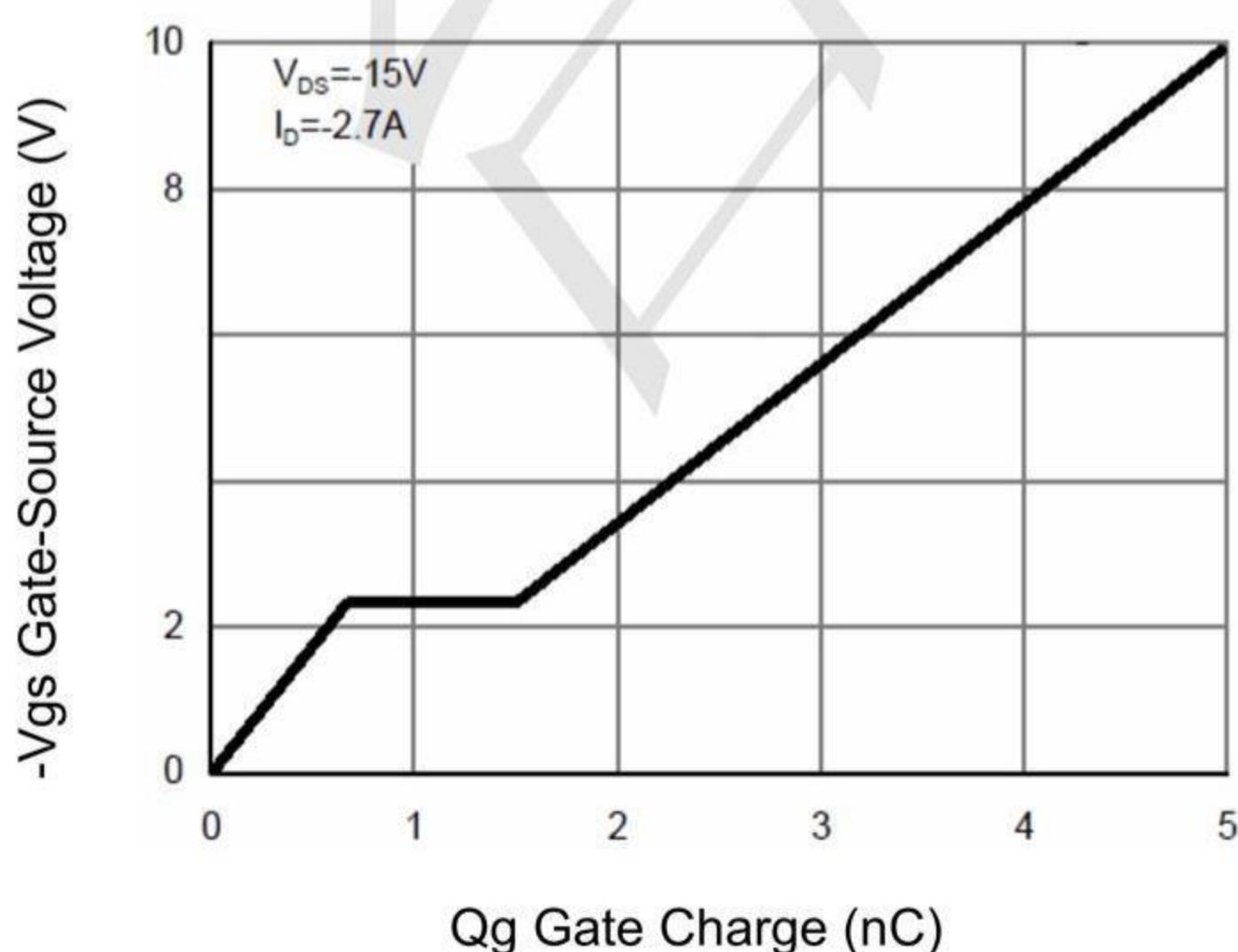
**Figure 6 Drain-Source On-Resistance**



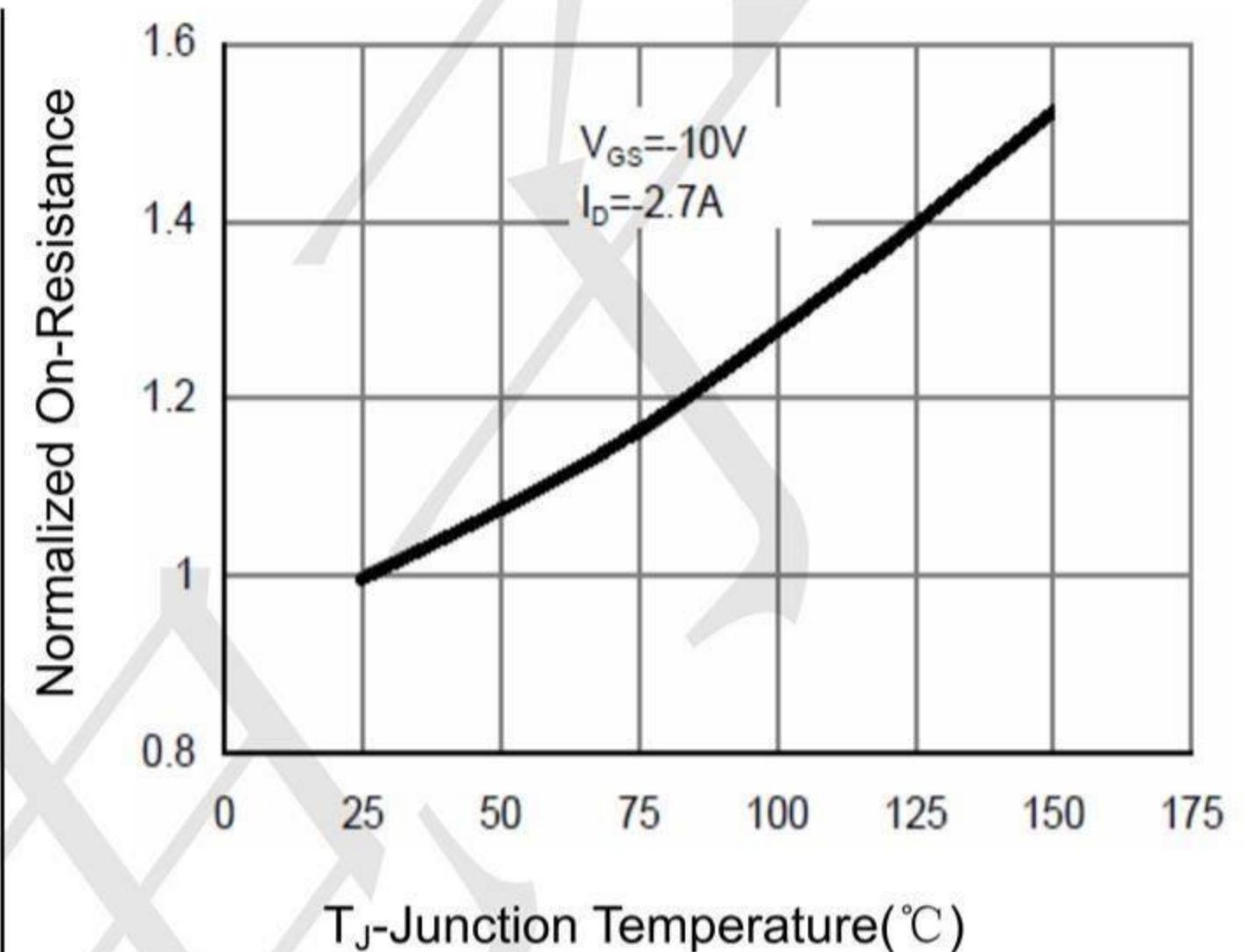
**Figure 7 Transfer Characteristics**



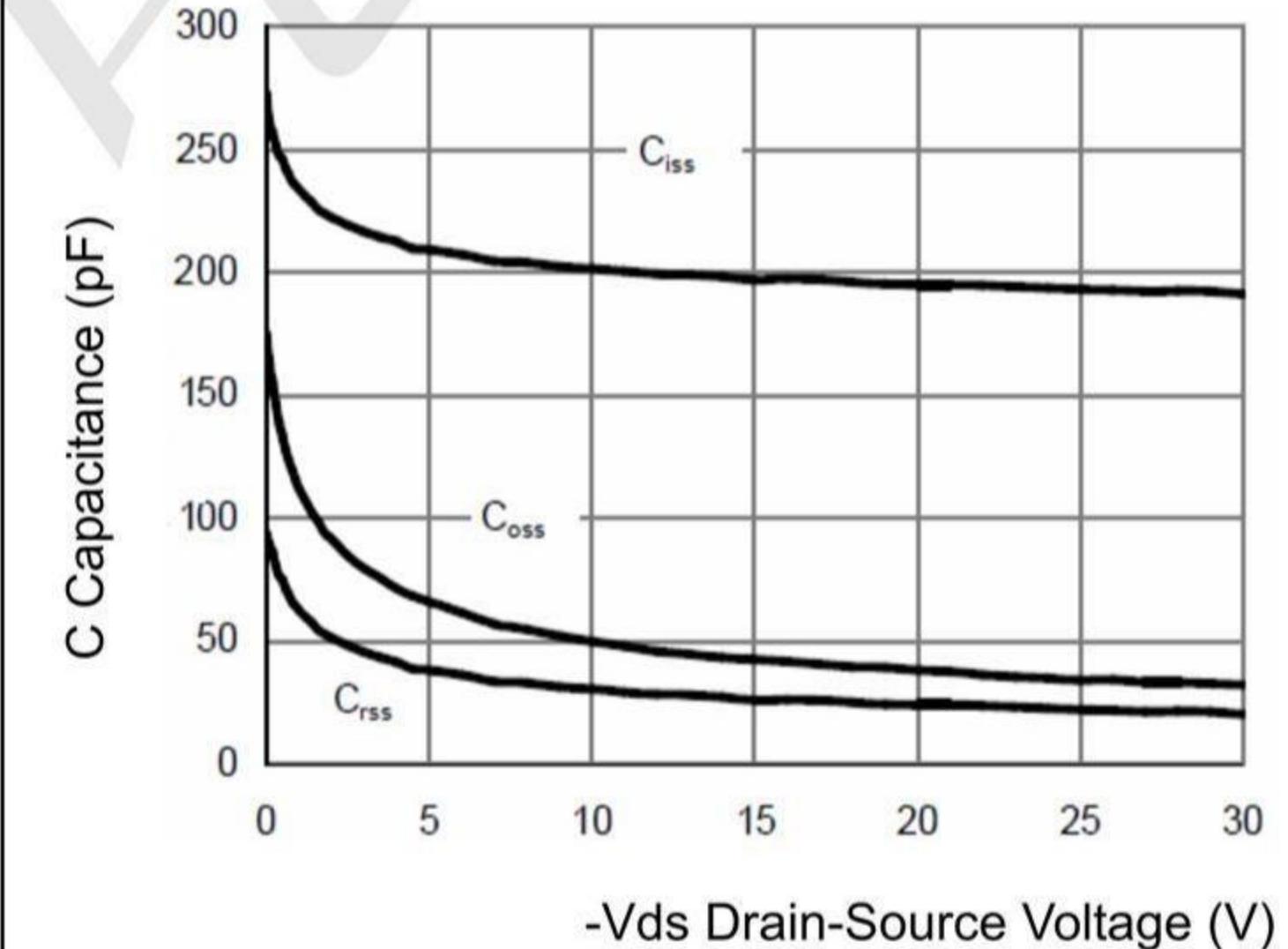
**Figure 9 Rdson vs Vgs**



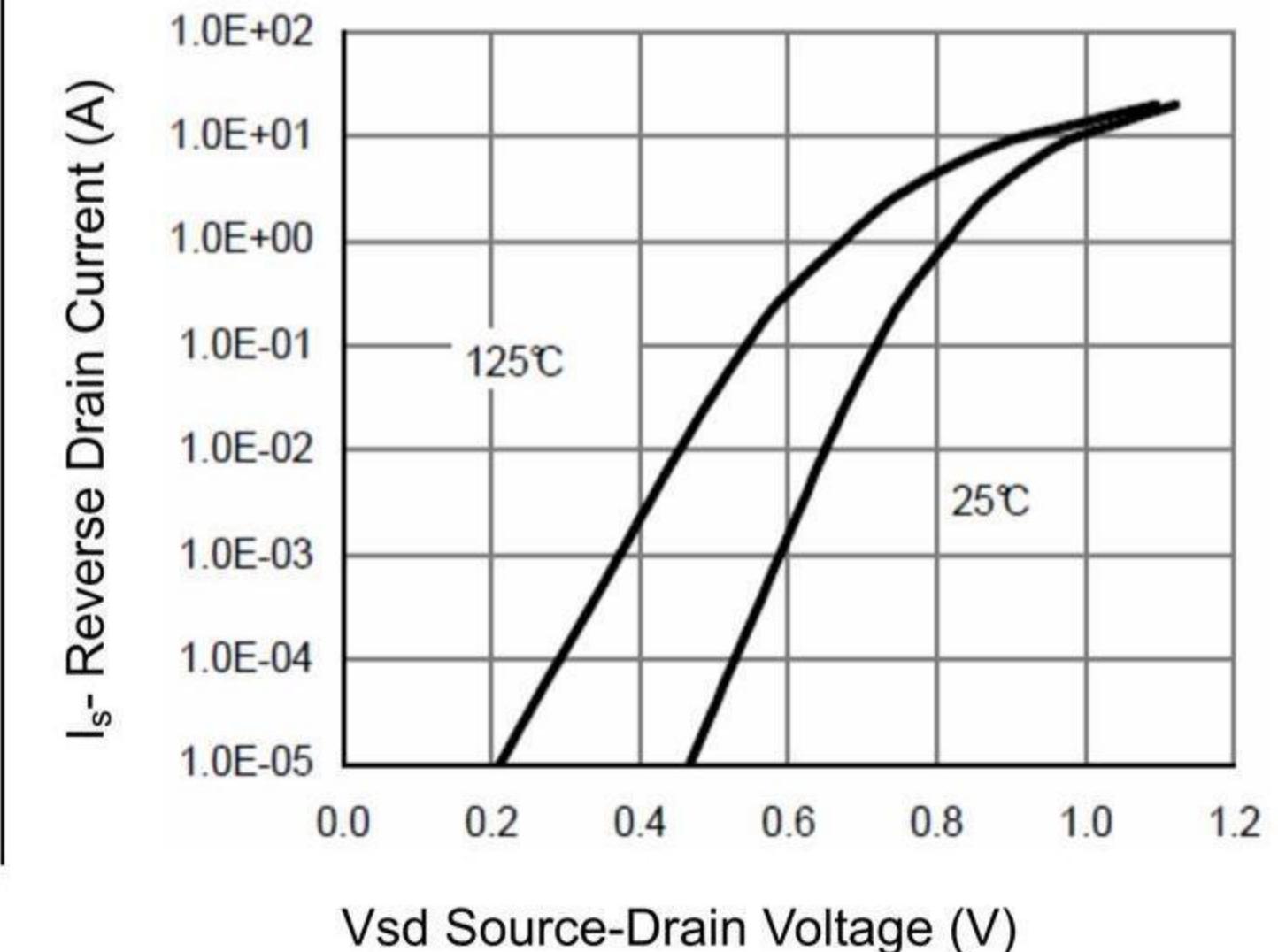
**Figure 11 Gate Charge**



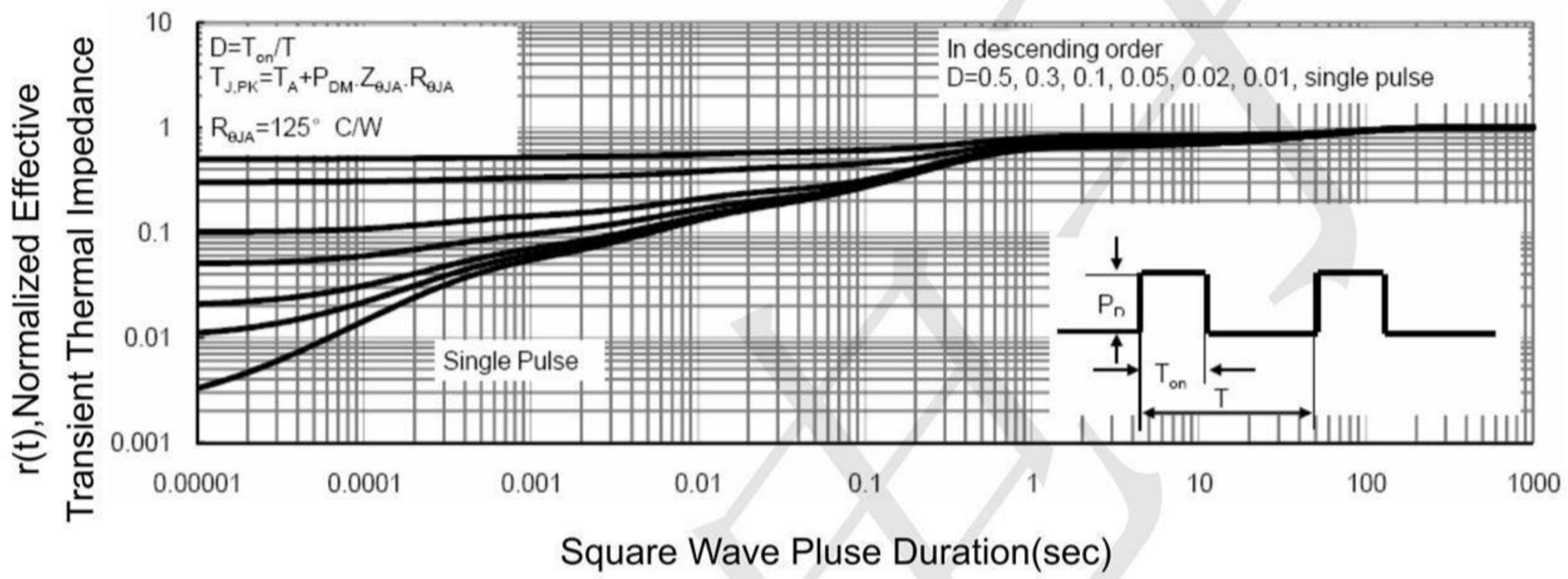
**Figure 8 Drain-Source On-Resistance**



**Figure 10 Capacitance vs Vds**



**Figure 12 Source-Drain Diode Forward**



**Figure 13 Normalized Maximum Transient Thermal Impedance**



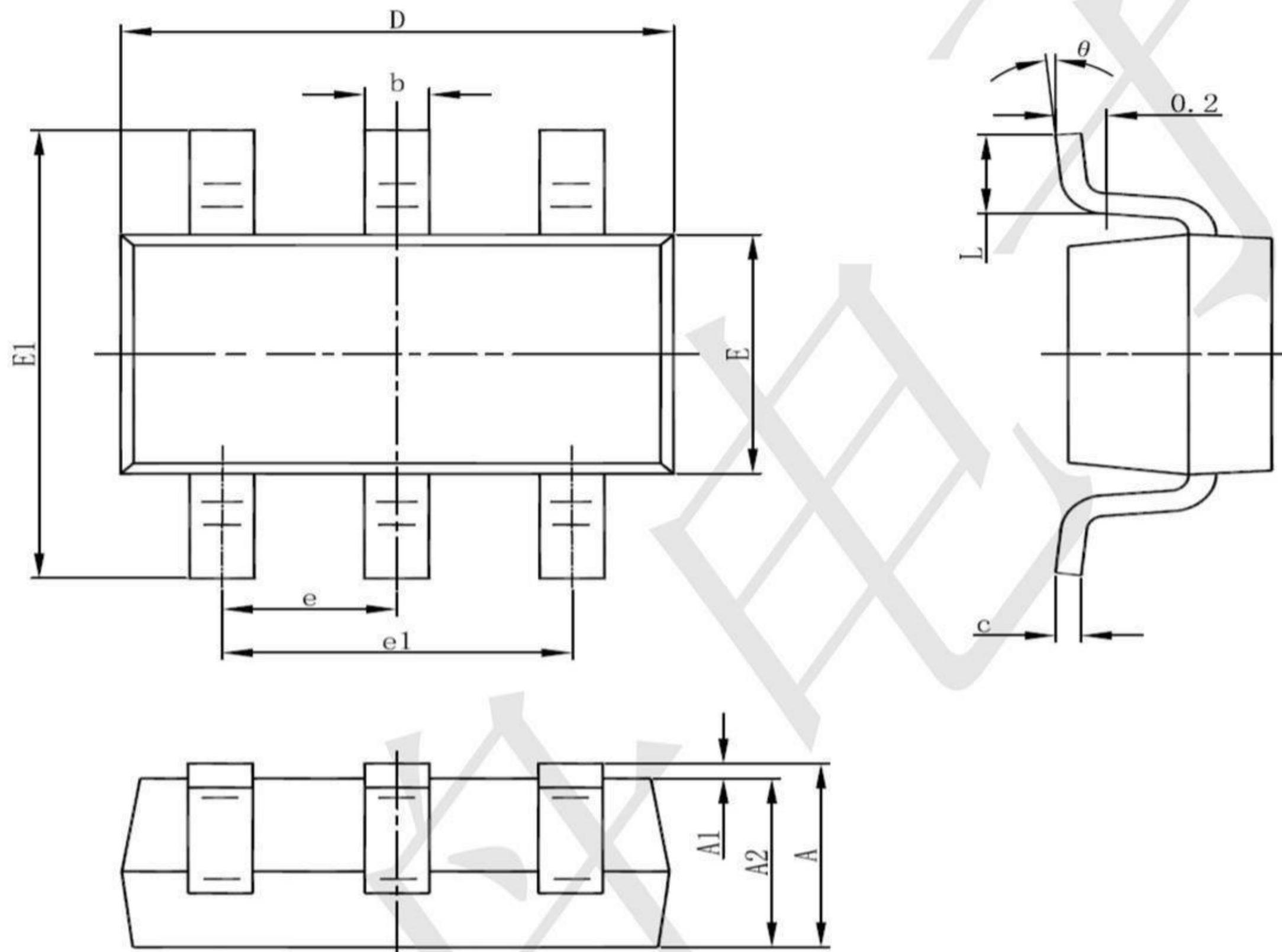
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**SI3590DV**

N and P-Channel Enhancement Mode Power MOSFET

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**SOT23-6 Package Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

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